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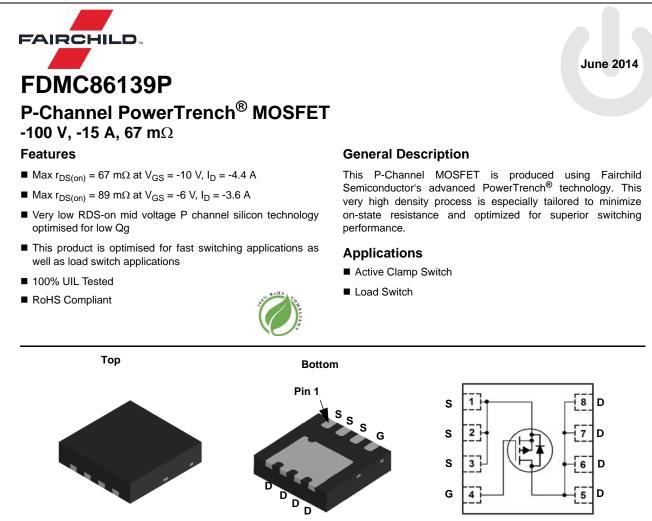


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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MLP 3.3x3.3

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			-100	V
V _{GS}	Gate to Source Voltage			±25	V
	Drain Current -Continuous	T _C = 25 °C		-15	
I _D	-Continuous	T _A = 25 °C	(Note 1a)	-4.4	А
	-Pulsed		-30		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	121	mJ
D	Power Dissipation	T _C = 25 °C		40	w
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	VV
T _J , T _{STG}	Operating and Storage Junction Tempera	ture Range		-55 to + 150	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	3.1	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note	1a) 53	C/ VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC86139P	FDMC86139P	Power 33	13 "	12 mm	3000 units

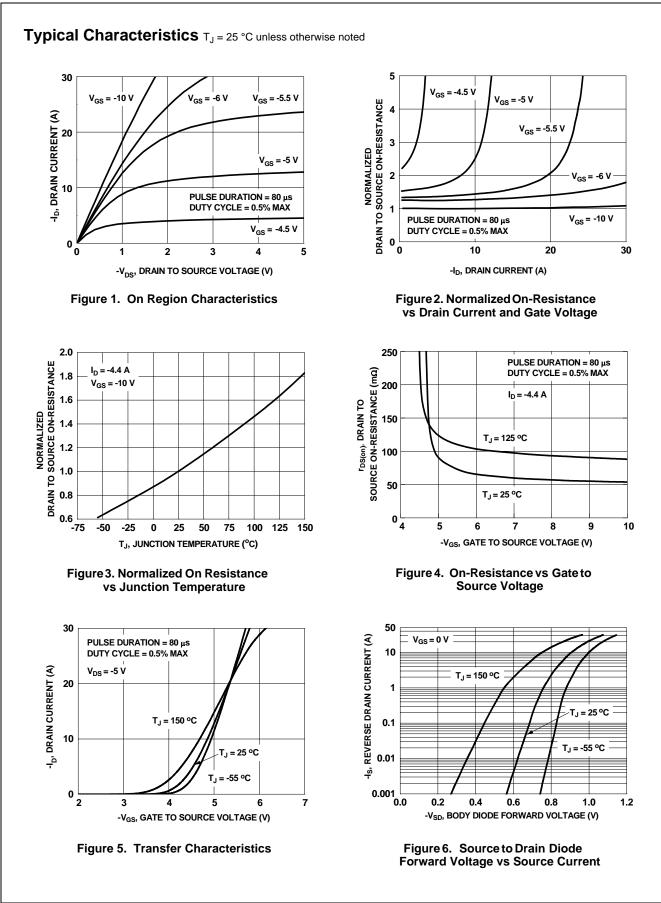
FDMC86139P P-Channel PowerTrench[®] MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = -250 μA, V _{GS} = 0 V	-100			V
ΔBV_{DSS} ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referenced to 25 °C		-63		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 V, V_{DS} = 0 V$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$	-2	-3	-4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{I}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, referenced to 25 °C		7		mV/°C
<u> </u>		V _{GS} = -10 V, I _D = -4.4 A		56	67	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = -6 \text{ V}, \text{ I}_{D} = -3.6 \text{ A}$		69	89	mΩ
		$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -4.4 \text{ A}, \text{T}_{J} = 125 \text{ °C}$		87	104	
9 _{FS}	Forward Transconductance	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -4.4 \text{ A}$		12		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			1001	1335	pF
C _{oss}	Output Capacitance	$V_{DS} = -50 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$		178	240	pF
C _{rss}	Reverse Transfer Capacitance	f = 1 MHz		10	15	pF
R _g	Gate Resistance		0.1	1.6	3.2	Ω
×	Characteristics	- <u>-</u>			1	1
t _{d(on)}	Turn-On Delay Time			11	20	ns
t _r	Rise Time	V _{DD} = -50 V, I _D = -4.4 A,		2.5	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -10 V, R_{GEN} = 6 \Omega$		17	30	ns
t _f	Fall Time			4	10	ns
Q _{g(TOT)}	Total Gate Charge	$V_{CS} = 0 V \text{ to } -10 V$		16	22	nC
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } -10 V$ $V_{GS} = 0 V \text{ to } -6 V$ $I_D = -50 V,$ $I_D = -4.4 A$		9.8	14	nC
Q _{gs}	Total Gate Charge	I _D = -4.4 A		4.5		nC
Q _{gd}	Gate to Drain "Miller" Charge	-		3.2		nC
	urce Diode Characteristics					
		$V_{GS} = 0 V, I_{S} = -4.4 A$ (Note 2)		-0.84	-1.3	V
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -1.9 A$ (Note 2)		-0.79	-1.2	V
t _{rr}	Reverse Recovery Time	I = 4.4.0 di/dt = 100.0/up		70	112	ns
Q _{rr}	Reverse Recovery Charge	- I _F = -4.4 A, di/dt = 100 A/μs		141	225	nC
NOTES: I. R _{θJA} is determ the user's boa		ad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is gu	b) 125 °C			termined b

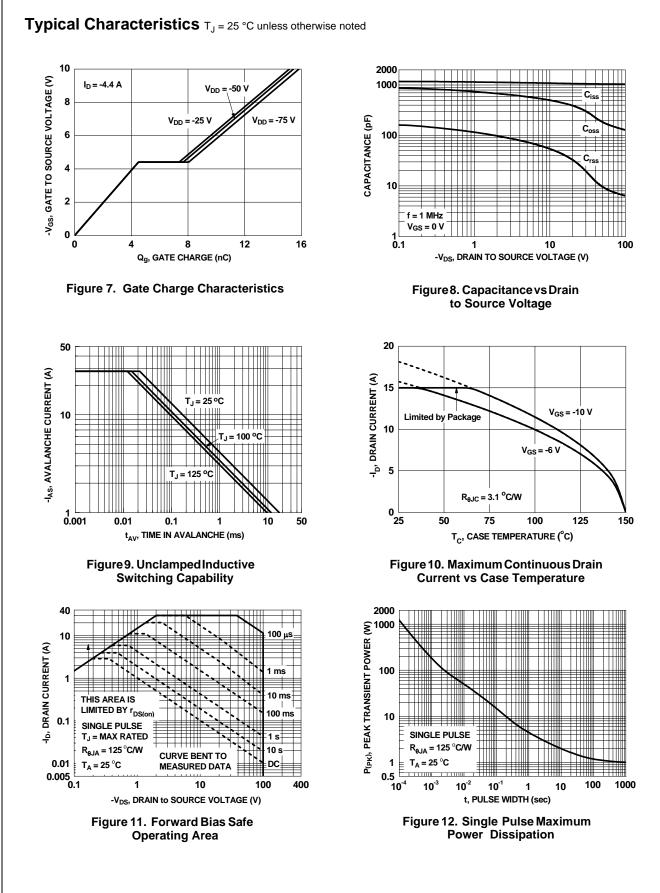
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

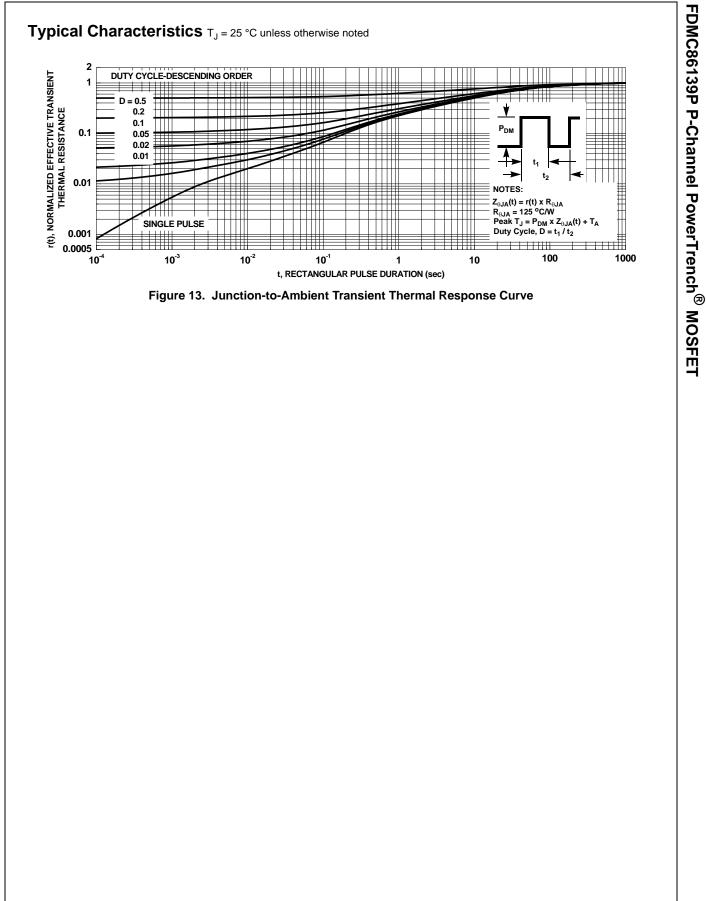
3. Starting T_J = 25 °C; P-ch: L = 3 mH, I_{AS} = -9 A, V_{DD} = -100 V, V_{GS} = -10 V. 100% test at L = 0.1 mH, I_{AS} = -28 A.

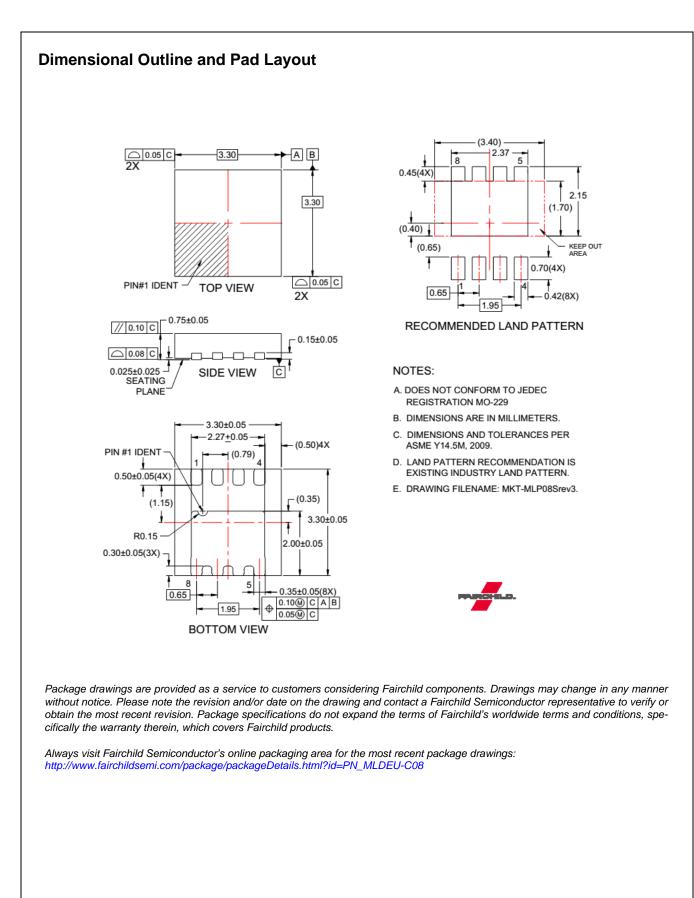
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